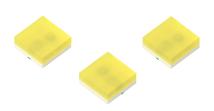






0.65 x 0.65 x 0.25 mm Bi-Color Surface Mount LED



DESCRIPTIONS

- The source color devices are made with InGaN on Sapphire substrate Light Emitting Diode
- The Super Bright Yellow source color devices are made with AlGaInP on GaAs substrate Light Emitting
- · Electrostatic discharge and power surge could damage the LEDs
- It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- All devices, equipments and machineries must be electrically grounded

FEATURES

- 0.65 mm x 0.65 mm SMD LED, 0.25 mm thickness
- Low power consumption
- Package: 4000 pcs / reel
- Moisture sensitivity level: 3
- · Halogen-free
- RoHS compliant

APPLICATIONS

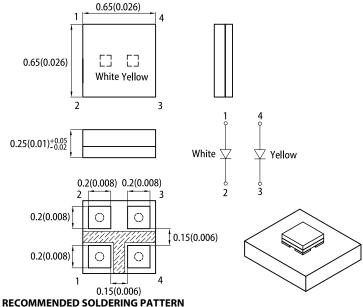
- Backlight
- · Status indicator
- · Home and smart appliances
- · Wearable and portable devices
- · Healthcare applications

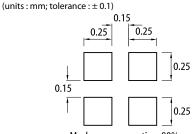
ATTENTION

Observe precautions for handling electrostatic discharge sensitive devices



PACKAGE DIMENSIONS





Mask open area ratio: 80% Mask thickness: 80~100um

- All dimensions are in millimeters (inches).
 Tolerance is ±0.1(0.004") unless otherwise noted.
- The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

 The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	Emitting Color		Iv (mcd) @ 5mA [2]		Viewing Angle [1]
	(Material)	Lens Type	Min.	Тур.	201/2
KPGB-0607VWA1SYKF-TT	White (InGaN)	Vallau Fluoroana	30	165	
	Super Bright Yellow (AlGaInP)	Yellow Fluorescent	4	20	140°

Notes.

1. 61/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.

2. Luminous intensity / luminous flux: +/-15%.

3. Luminous intensity value is traceable to CIE127-2007 standards.







ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C (WHITE)

Parameter	Symbol	Emitting Color	Value		Unit
Farameter	Symbol Emitting Color		Тур.	Тур. Мах.	
Chromaticity Coordinates x $I_F = 5mA$	x ^[1]	White	0.31	-	-
Chromaticity Coordinates y I _F = 5mA	y ^[1]	White	0.31	-	-
Capacitance	С	White	100	-	pF
Forward Voltage I _F = 5mA	V _F ^[2]	White	2.9	3.2	V
Reverse Current (V _R = 5V)	I _R	White	-	50	μΑ
Temperature Coefficient of x $I_F = 5\text{mA}$, -10°C \leq T \leq 85°C	TC _X	White	-0.18	-	10 ⁻³ /°C
Temperature Coefficient of y $I_F = 5 m A, -10 ^{\circ} C \leq T \leq 85 ^{\circ} C$	TC _Y	White	-0.19	-	10 ⁻³ /°C
Temperature Coefficient of V_F I_F = 5mA, -10°C \leq T \leq 85°C	TC _V	White	-3.0	-	mV/°C

Notes:

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C (YELLOW)

Parameter	Sumbol Emitting Color	Value		- Unit	
Parameter	Symbol	Symbol Emitting Color		Тур. Мах.	
Wavelength at Peak Emission I _F = 5mA	$\lambda_{ m peak}$	Super Bright Yellow	Super Bright Yellow 591		nm
Dominant Wavelength I _F = 5mA	λ _{dom} ^[1]	Super Bright Yellow	Super Bright Yellow 589		nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 5mA	Δλ	Super Bright Yellow	15	-	nm
Capacitance	С	Super Bright Yellow	Super Bright Yellow 25		pF
Forward Voltage I _F = 5mA	V _F ^[2]	Super Bright Yellow	1.97	2.3	V
Reverse Current (V _R = 5V)	I _R	Super Bright Yellow	-	10	μΑ
Temperature Coefficient of λ_{peak} I_F = 5mA, -10°C \leq T \leq 85°C	$TC_{\lambda peak}$	Super Bright Yellow	0.12	-	nm/°C
Temperature Coefficient of λ_{dom} I_F = 5mA, -10°C \leq T \leq 85°C	TC _{λdom}	Super Bright Yellow	0.07	-	nm/°C
Temperature Coefficient of V_F I_F = 5mA, -10°C \leq T \leq 85°C	TC _V	Super Bright Yellow	-2.0	-	mV/°C

Notes.

1. Measurement tolerance of the chromaticity coordinates is ±0.01.

2. Forward voltage: ±0.1V.

3. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

^{1.} The dominant wavelength (λd) above is the setup value of the sorting machine. (Tolerance λd: ±1nm.)
2. Forward voltage: ±0.1V.
3. Wavelength value is traceable to CIE127-2007 standards.
4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.





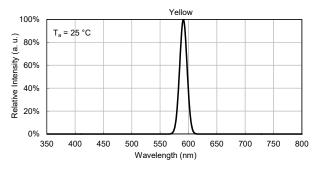


ABSOLUTE MAXIMUM RATINGS at T_A=25°C

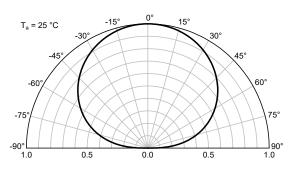
Parameter	Symbol	Va	Value		
Farameter	Symbol	White	Super Bright Yellow	Unit	
Power Dissipation	P _D ^[1]	35		mW	
Reverse Voltage	V _R	5 5		V	
Junction Temperature	Tj	115	115	°C	
Operating Temperature	T _{op}	-40 to +85		°C	
Storage Temperature	T _{stg}	-40 to +100		°C	
DC Forward Current	I _F ^[2]	10 10		mA	
Peak Forward Current	I _{FP} ^[3]	50	50	mA	
Electrostatic Discharge Threshold (HBM)	_	250 3000		V	
Thermal Resistance (Junction / Ambient)	R _{th JA} ^[4]	720 690		°C/W	
Thermal Resistance (Junction / Solder point)	R _{th JS} ^[4]	580	530	°C/W	

TECHNICAL DATA

RELATIVE INTENSITY vs. WAVELENGTH



SPATIAL DISTRIBUTION



Notes:

1. Within 35mW when multiple chips are lightened

2. The maximum ratings are valid for the case of lighting a single chip
When two chips are lit at the same time, each chip should be driven at a current lower than 50% of the absolute maximum ratings

3. Duty Cycle ≤ 1 / 20, Pulse Width = 1ms.

4. R<sub>th, 14, R_{th, 15} Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad).

5. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.</sub>



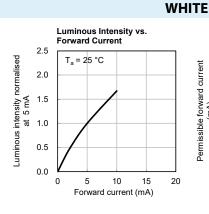


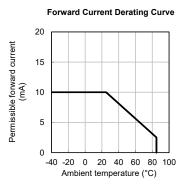
TECHNICAL DATA

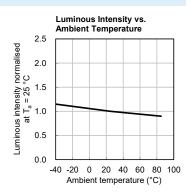
Forward Current vs. Forward Voltage 20 T_a = 25 °C Forward current (mA) 15 10 5

2.3 2.5 2.7 2.9 3.1 3.3 3.5

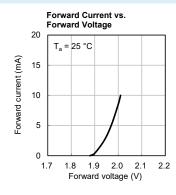
Forward voltage (V)

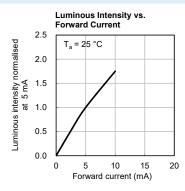


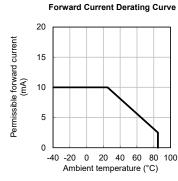


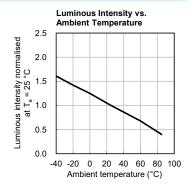


SUPER BRIGHT YELLOW

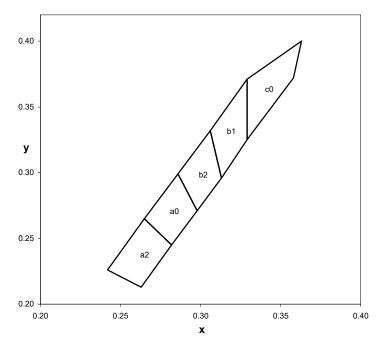








CIE CHROMATICITY DIAGRAM



	x	у		х	у
a2	0.263	0.213	a0	0.282	0.245
	0.282	0.245		0.298	0.271
	0.265	0.265	au	0.286	0.299
	0.242	0.226		0.265	0.265
b2	0.298	0.271	b1	0.313	0.296
	0.313	0.296		0.329	0.325
	0.306	0.332		0.329	0.371
	0.286	0.299		0.306	0.332
c0	0.329	0.325			
	0.358	0.372			
	0.363	0.400			
	0.329	0.371			

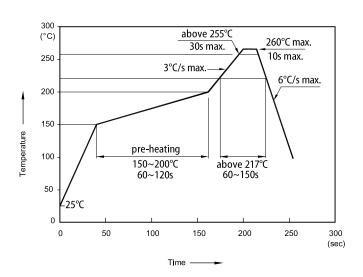
Notes. Shipment may contain more than one chromaticity regions. Orders for single chromaticity region are generally not accepted. Measurement tolerance of the chromaticity coordinates is ±0.01.





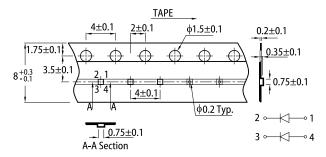


REFLOW SOLDERING PROFILE for LEAD-FREE SMD PROCESS

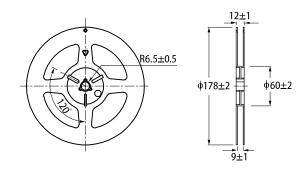


- Don't cause stress to the LEDs while it is exposed to high temperature.
 The maximum number of reflow soldering passes is 2 times.
 Reflow soldering is recommended. Other soldering methods are not recommended as they might cause damage to the product.

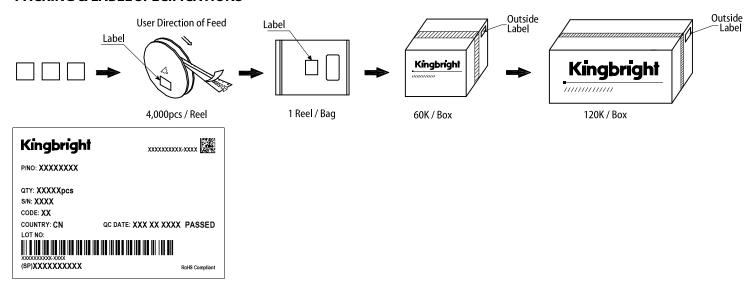
TAPE SPECIFICATIONS (units:mm)



REEL DIMENSION (units: mm)



PACKING & LABEL SPECIFICATIONS



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- The part number, type, and specifications mentioned in this document are subject to future change and improvement without notice. Before production usage customer should refer to the latest datasheet for the updated specifications.
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